

2N1026 Transistors

Si PNP Lo-Pwr BJT

Military/High-Rel N

$V_{(BR)CEO}$ (V) 35

$V_{(BR)CBO}$ (V) 40

I_C Max. (A) 100m

Absolute Max. Power Diss. (W) 250m

Maximum Operating Temp ($^{\circ}C$) 175 \bar{o}

I_{CBO} Max. (A) 25n

@ V_{CBO} (V) (Test Condition) 35

$V_{(CE)sat}$ Max. (V)

@ I_C (A) (Test Condition)

@ I_B (A) (Test Condition)

h_{FE} Min. Current gain.

h_{FE} Max. Current gain.

@ I_C (A) (Test Condition)

@ V_{CE} (V) (Test Condition)

f_T Min. (Hz) Transition Freq 2.0M:

@ I_C (A) (Test Condition) 1.0m

@ V_{CE} (V) (Test Condition) 6.0

$C_{(obo)}$ (Max) (F) 7.0p

@ V_{CB} (V) (Test Condition) 6.0

@Freq. (Hz) (Test Condition)

Datasheet.Live